



[54] DYNAMIC SEMICONDUCTOR MEMORY DEVICE AND METHOD FOR INITIALIZING A DYNAMIC SEMICONDUCTOR MEMORY DEVICE

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[52] U.S. Cl. 365/226; 365/228

[58] Field of Search 365/226, 227, 365/228

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Attorney, Agent, or Firm—Herbert L. Lerner; Laurence A. Greenber; Werner H. Stemer

[57] ABSTRACT

A dynamic semiconductor memory device of a random access type has an initialization circuit that controls the switching-on operation of the semiconductor memory device and of its circuit components. The initialization circuit supplies a supply voltage stable signal once the supply voltage has been stabilized after the switching-on of the semiconductor memory device. The initialization circuit has an enable circuit that receives the supply voltage stable signal and further command signals externally applied to the semiconductor memory device. The enable circuit supplies an enable signal after a predetermined proper initialization sequence of the command signals applied to the semiconductor memory device is identified. The enable signal effects the unlatching of a control circuit provided for the proper operation of the semiconductor memory device.

13 Claims, 3 Drawing Sheets

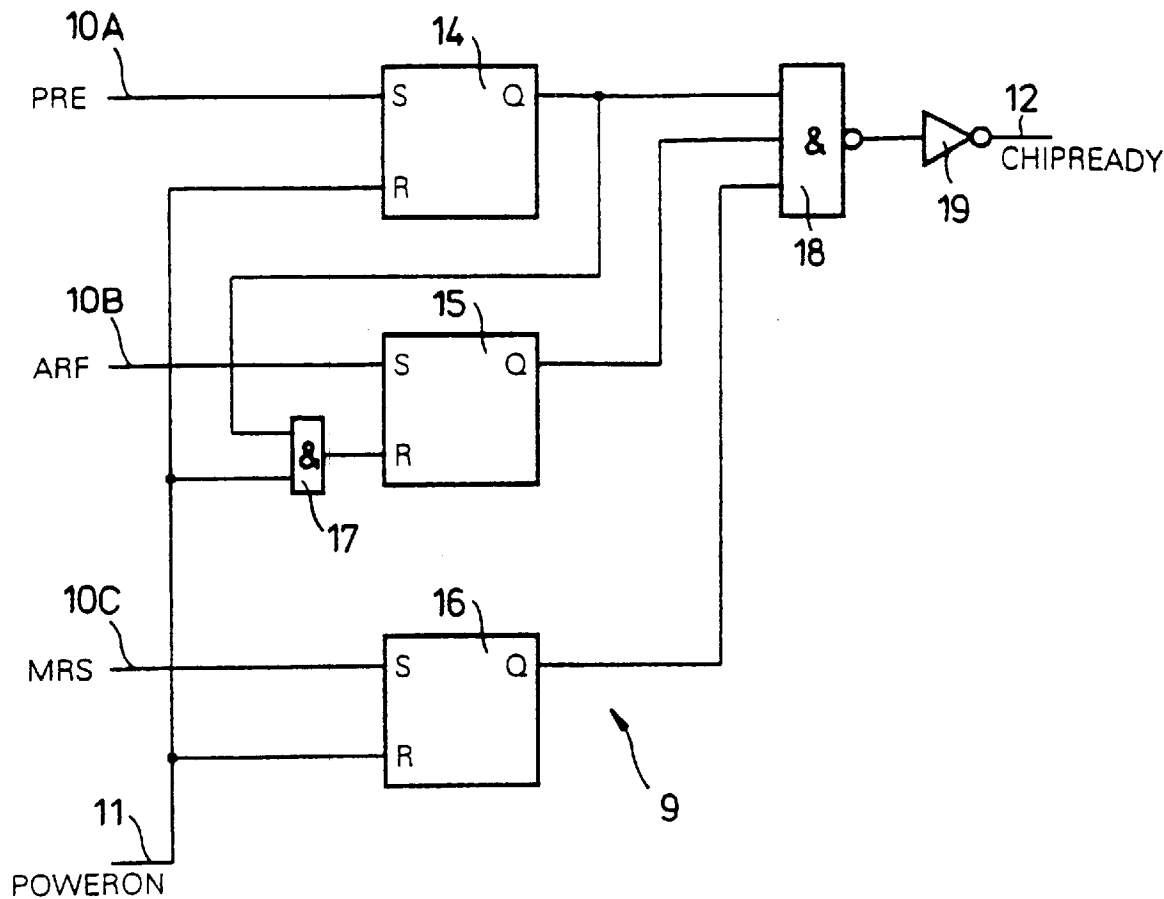
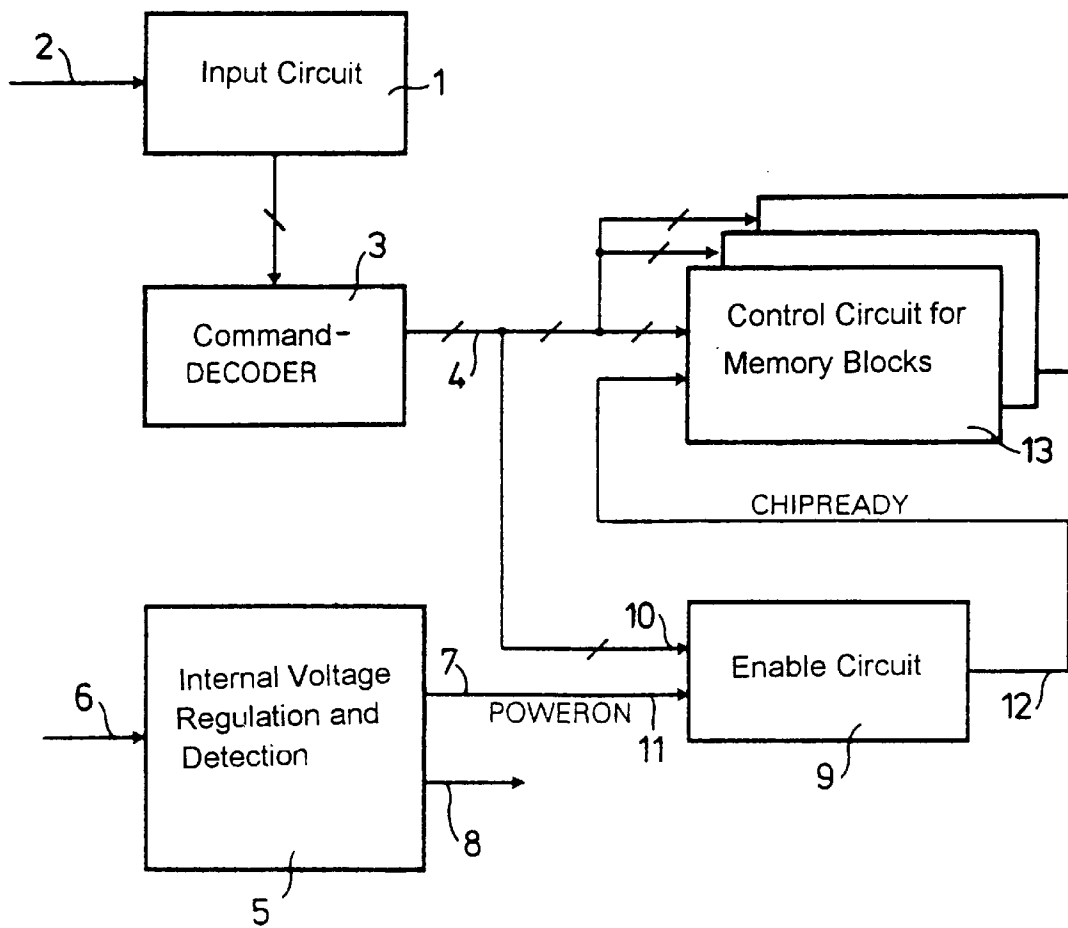


Fig 1



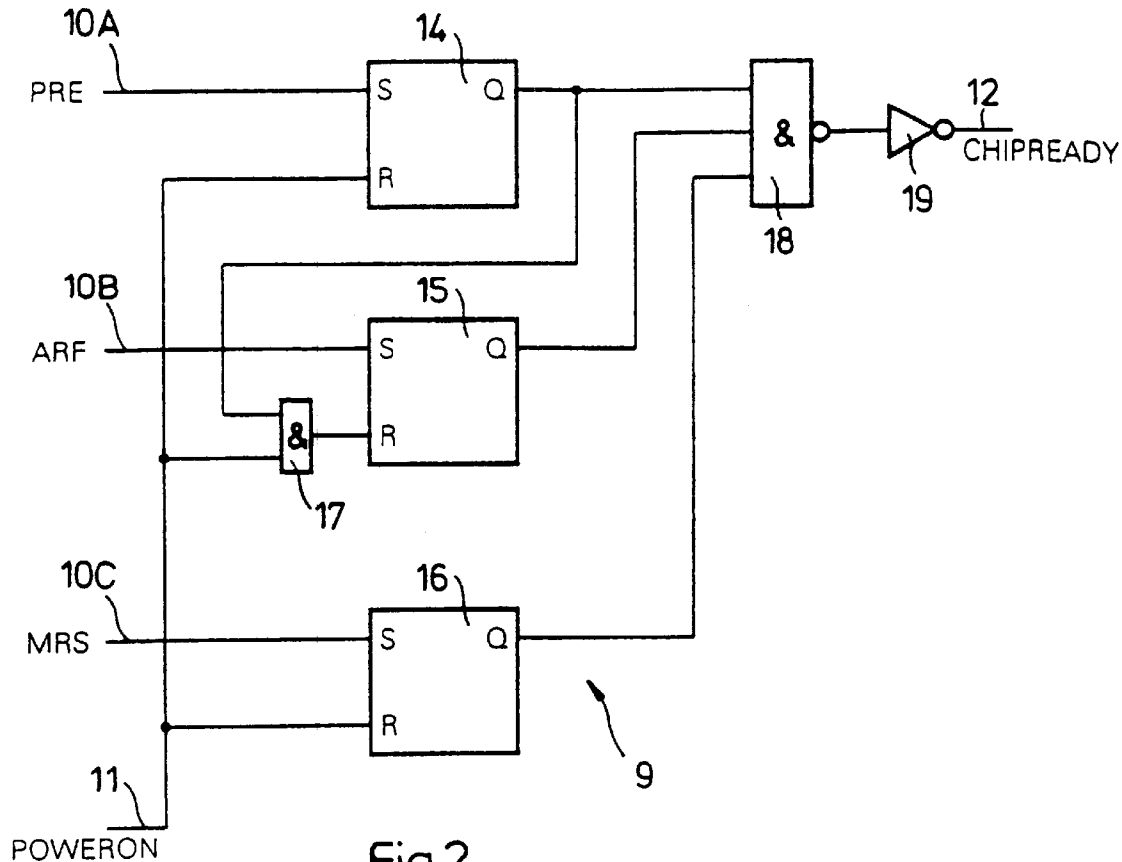


Fig 2

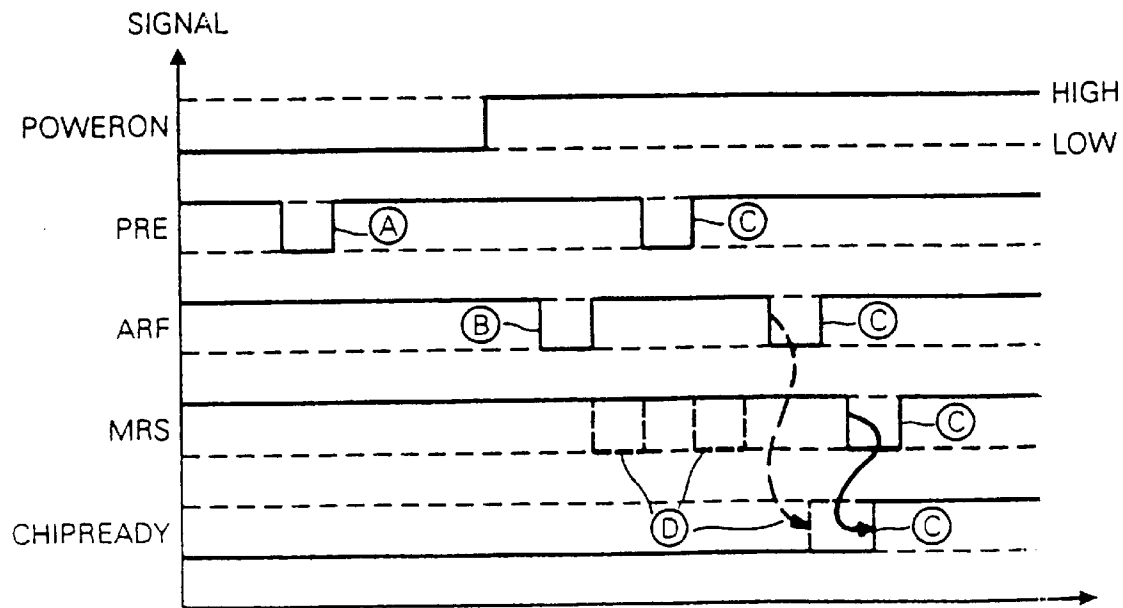


Fig 3

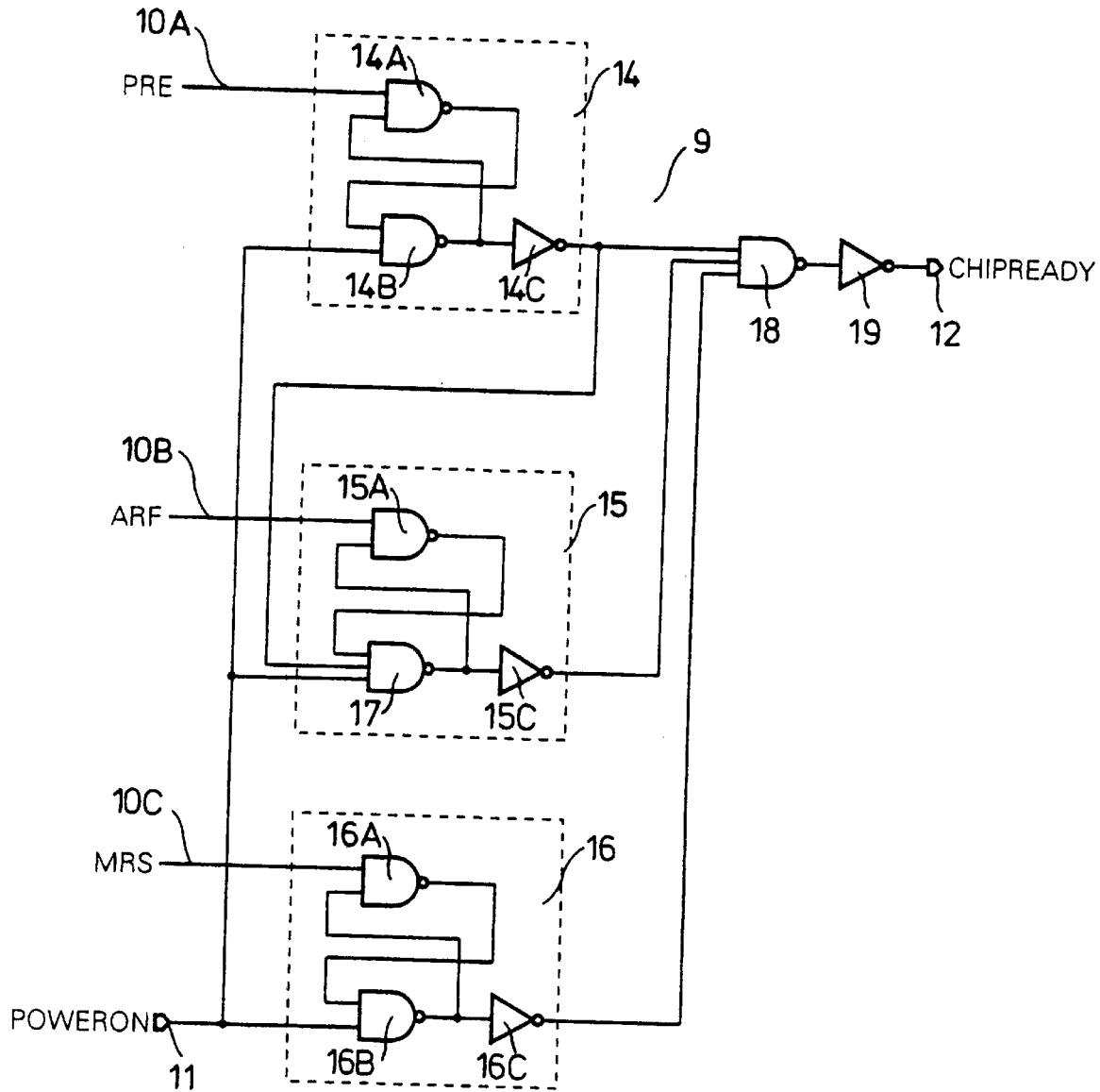


Fig 4

**DYNAMIC SEMICONDUCTOR MEMORY
DEVICE AND METHOD FOR INITIALIZING
A DYNAMIC SEMICONDUCTOR MEMORY
DEVICE**

BACKGROUND OF THE INVENTION

Field of the Invention

The invention relates to a dynamic semiconductor memory device of the random access type (DRAM/SDRAM) having an initialization circuit which controls a switching-on operation of the semiconductor memory device and of its circuit components. The initialization circuit supplies a supply voltage stable signal (POWERON) once a supply voltage has been stabilized after the switching-on of the semiconductor memory device. The invention also relates to a method for initializing such a dynamic semiconductor memory device, and also to the use of an enable circuit, that supplies an enable signal, for controlling the switching-on operation of the dynamic semiconductor memory device.

In the case of SDRAM semiconductor memories according to the JEDEC standard, it is necessary to ensure during the switch-on operation ("POWERUP") that the internal control circuits provided for the proper operation of the semiconductor memory device are reliably held in a defined desired state, in order to prevent undesirable activation of output transistors that would cause, on the data lines, a short circuit (so-called "bus contention" or "data contention") or uncontrolled activation of internal current loads. The solution to the problem turns out to be difficult on account of a fundamental unpredictability of the time characteristic of the supply voltage and of the voltage level or levels at the external control inputs during the switch-on operation of the semiconductor memory. According to the specifications of the manufacturer an SDRAM component should ignore all commands which are present chronologically before a defined initialization sequence. The sequence consists of predetermined commands that must be applied in a defined chronological order. However, a series of functions and commands which are allowed during proper operation of the component are desired or allowed chronologically only after the initialization sequence. According to the JEDEC standard for SDRAM semiconductor memories, a recommended initialization sequence (so-called "POWERON-SEQUENCE") is provided as follows:

- a. the application of a supply voltage and a start pulse in order to maintain an NOP condition at the inputs of the component;
- b. the maintenance of a stable supply voltage of a stable clock signal, and of stable NOP input conditions for a minimum time period of 200 us;
- c. the preparation command for word line activation (PRECHARGE) for all the memory banks of the device;
4. the activation of eight or more refresh commands (AUTOREFRESH); and
5. the activation of a loading configuration register command (MODE-REGISTER-SET) for initializing the mode register.

After the identification of such a defined initialization sequence, the memory module is normally in a so-called IDLE state, that is to say it is precharged and prepared for proper operation. In the case of the SDRAM semiconductor memory modules that have been disclosed to date, all the control circuits of the component have been unlatched only

with the POWERON signal. The signal POWERON is active if the internal supply voltages have reached the necessary values that are necessary for the proper operation of the component. The module is then in a position to recognize and execute instructions.

SUMMARY OF THE INVENTION

It is accordingly an object of the invention to provide a dynamic semiconductor memory device and a method for initializing a dynamic semiconductor memory device which overcome the above-mentioned disadvantages of the prior art methods and devices of this general type, which is as simple as possible in structural terms and which effectively prevents the risk of a short circuit of the data lines and/or uncontrolled activation of internal current loads.

With the foregoing and other objects in view there is provided, in accordance with the invention, a dynamic semiconductor memory device of a random access type, containing an initialization circuit controlling a switching-on operation and supplying a supply voltage stable signal once a supply voltage has been stabilized after the switching-on operation. The initialization circuit has a control circuit for controlling operations and an enable circuit receiving the supply voltage stable signal and externally applied further command signals. The enable circuit outputting an enable signal after a predetermined proper initialization sequence of the externally applied further command signals are identified and the enable signal effecting an unlatching of the control circuit.

The invention provides for the initialization circuit to have an enable circuit, which receives the supply voltage stable signal and the externally applied further command signals. The enable circuit generates the enable signal after the identification of the predetermined proper initialization sequence of the command signals is achieved. The enable signal effects the unlatching of the control circuit provided for the proper operation of the semiconductor memory device.

Following the principle of the invention, the enable signal (CHIPREADY) is generated and becomes active in dependence on further internal signals and the initialization sequence and then unlatches predetermined circuits. The predetermined circuits remain latched until the end of the predetermined initialization sequence. By way of example, commands are decoded but not executed and the output drivers are held at high impedance.

According to the preferred application in SDRAM memory devices according to the JEDEC standard, it is provided that the command signals, externally applied to the semiconductor memory device, of the initialization sequence are to be identified by the enable circuit. The command signals include a preparation command signal for word line activation (PRECHARGE), and/or a refresh command signal (AUTOREFRESH), and/or a loading configuration register command signal (MODE-REGISTER-SET).

According to an advantageous structural refinement of the initialization circuit according to the invention, it is provided that the enable circuit has at least one bistable multivibrator stage with a set input which receives the command signal (PRECHARGE, AUTOREFRESH, MODE-REGISTER-SET). The bistable multivibrator also has a reset input to which the supply voltage stable signal (POWERON), a signal derived therefrom, or a linked signal is applied. The bistable multivibrator further has an output at which the enable signal (CHIPREADY) is outputted.

In particular, the enable circuit has a plurality of bistable multivibrator stages respectively receiving the command signals.

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